PNP Epitaxial Planar Silicon Transistor

2SA1857



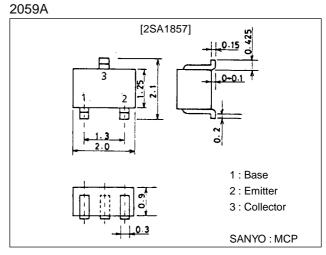
# FM, RF, MIX, IF Amplifier High-Frequency General-Purpose Amplifier Applications

### Features

- · High power gain : PG=25dB typ (f=100MHz).
- · High cutoff frequency :  $f_T=750MHz$  typ.
- $\cdot$  Low collector-to-emitter saturation voltage.
- $\cdot$  Complementary pair with the 2SC4400.

## Package Dimensions

unit:mm



# **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Symbol Conditions		Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		-15	V
Collector-to-Emitter Voltage	VCEO		-12	V
Emitter-to-Base Voltage	VEBO		-3	V
Collector Current	IC		-50	mA
Collector Dissipation	PC		150	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

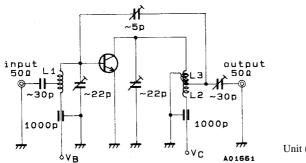
Parameter	Symbol	Conditions		Ratings				
Falameter	Symbol	Conditions		typ	max	Unit		
Collector Cutoff Current	ICBO	V <sub>CB</sub> =-12V, I <sub>E</sub> =0			-0.1	μA		
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =-2V, I <sub>C</sub> =0			-0.1	μA		
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-5mA	60*		270*			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =-10V, I <sub>C</sub> =-5mA		750		MHz		
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, f=1MHz		1.2	1.6	pF		
Reverse Transfer Caspacitance	Cre	V <sub>CB</sub> =-10V, f=1MHz		0.9		pF		
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-10mA, I <sub>B</sub> =-1mA		-0.1	-0.3	V		
Power Gain	PG	V <sub>CE</sub> =-10V, I <sub>C</sub> =-10mA, f=100MHz		25		dB		
* : The 2SA1857 is classified by 5mA h <sub>FE</sub> as follows : Marking : JS								
60 3 120 90 4	180 135	$h_{\rm FE}$ rank : 3, 4, 5						

	60	3	120	90	4	180	135	5	270	$\begin{bmatrix} h_{Fl} \end{bmatrix}$
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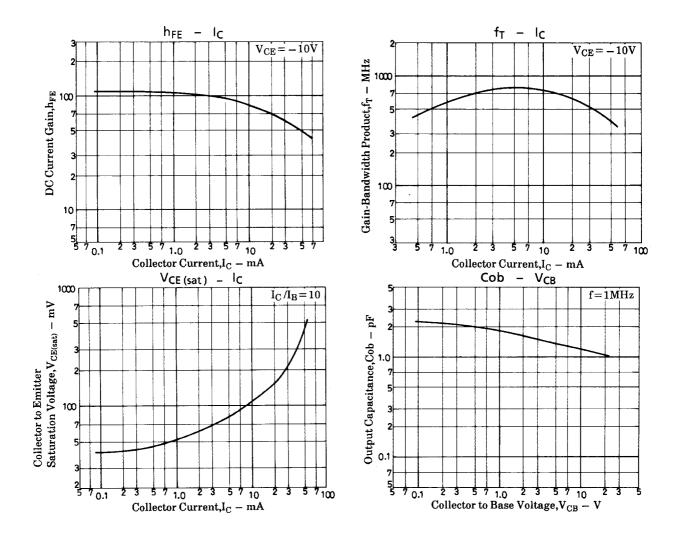
### **PG Test Circuit**

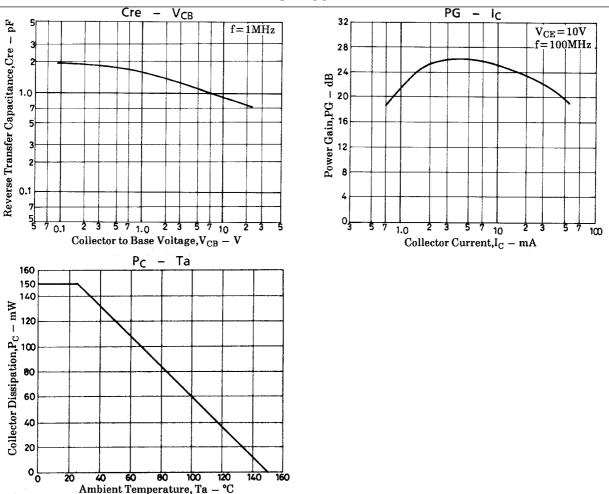


Unit (capacitance : F)

L1 : 1mmø plated wire 10mmø 5T, pitch 15mm, tap : 2T from base side L2 : 1mmø plated wire 10mmø 7T, pitch 10mm, tap : 2T from  $V_C$  side

L3 : 1mmø plated wire 10mmø 3T, pitch 10mm





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